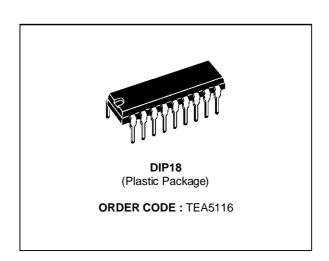


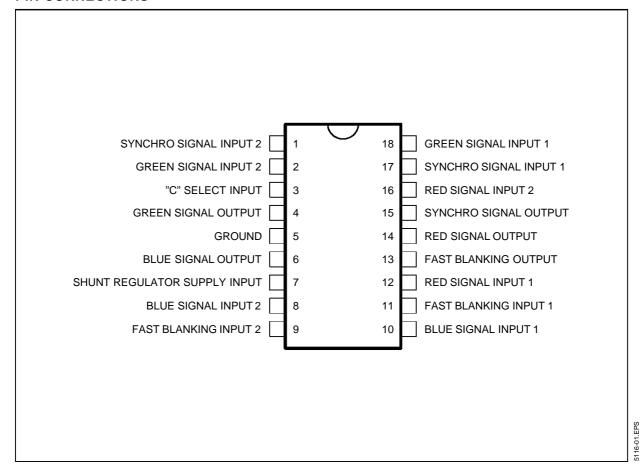
TEA5116

5 CHANNELS VIDEO SWITCH

- EACH CHANNEL EXCEPT FAST BLANKING HAS 6dB GAIN
- R, G, B AND VIDEO SIGNALS ARE CLAMPED TO THE SAME REFERENCE VOLTAGE IN OR-DER TO HAVE NO OUTPUT DIFFERENTIAL VOLTAGE WHEN SWITCHING
- ALL INPUT LEVELS COMPATIBLE WITH NFC 92250 AND EN 50049 NORMS
- 30MHz BAND WIDTH FOR R, G, B SIGNALS
- INTERNAL 6.7V SHUNT REGULATOR FOR:
 - _ LOW IMPEDANCE LOADS,
 - POWER DISSIPATION LIMITATION
- THE FIVE CHANNELS ARE SIMULTANE-OUSLY SWITCHED BY ONLY ONE SELECT INPUT

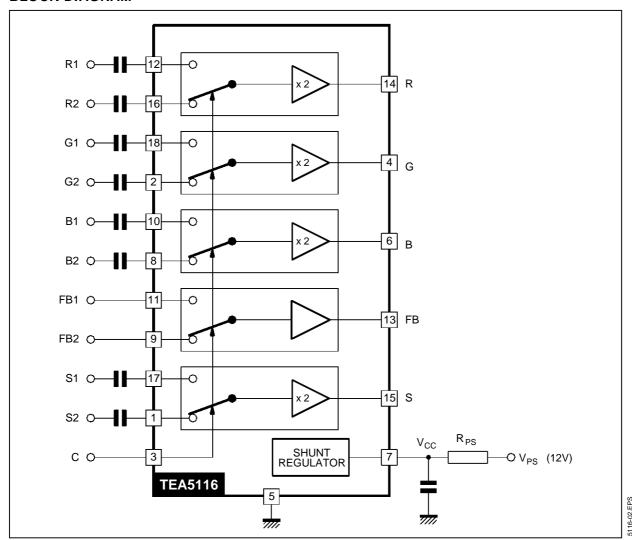


PIN CONNECTIONS



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BLOCK DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit	
Icc	Supply Current (see note)	150	mA	
V _{in}	Input Voltage (all inputs)	- 0.5 to V _{CC} + 0.5	V	
T _{oper}	Operating Temperature Range	0, 70	°C	
Tj	Junction Temperature	- 40, + 150	°C	
T _{stg}	Storage Temperature	- 40, + 150	°C	

Note: Minimum output load is 300 Ω in case of all outputs loaded.

THERMAL DATA

Symbol	Parameter	Value	Unit	32.TBL
R _{th (j-a)}	Junction-ambient Thermal Resistance	70	°C/W	5116-

ELECTRICAL CHARACTERISTICS

 T_{amb} = + 25 °C, $~I_{CC}$ = 120 mA ; Load value = 150 Ω (sequentially switched) (unless otherwise specified, refer to test circuit page 7)

Symbol	Parame	Min.	Тур.	Max.	Unit	
Vcc	Internal Shunt Regulator	I_{CC} = 120 mA I_{CC} = 90 mA I_{CC} = 150 mA	6.3 6.2 6.2	6.7	7.2 7.3 7.3	V V

R, G, B Switches (pins 4, 6, 14) (Time Measurement Conditions : Δ inputs RGB = 0.7 V_{pp} ; C pulse amplitude = 3 V)

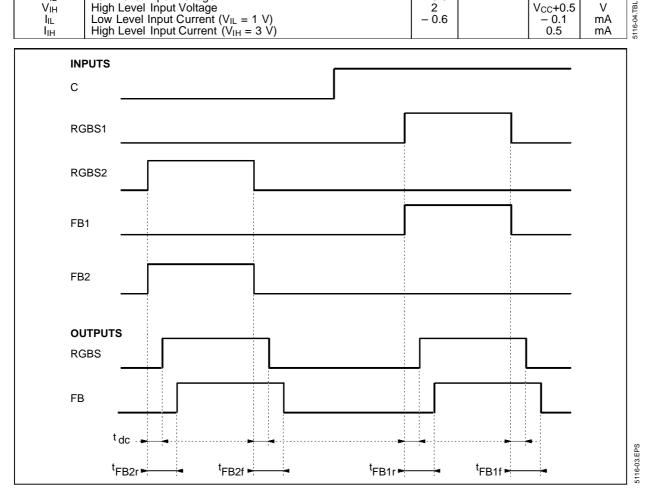
V _C	$ \begin{array}{ll} \text{DC Output Voltage} & \text{$T_{junction} = 25 \ ^{\circ}C$} \\ \text{(no input voltage)} & \text{$T_{junction}$ stabilized} \end{array} $		0.9 1.2	1.25	V
V _{AC}	Max Output Swing Voltage	2	4		V_{pp}
В	Bandwidth (- 3dB) (input voltage 0.7Vpp)	20	30		MHz
A _v	Gain of Each Channel (input voltage 0.7V _{pp} ; f = 1MHz)	5.5	6	6.5	dB
A _{dc}	Gain Difference between any two R, G, B Channels (input voltage $0.7V_{pp}$; f = 1MHz)		0.1	0.5	dB
	Input Swing		0.7 V ± 3dB		
Zic	DC Input Impedance		10		kΩ
Z _{oc}	Dynamic Output Impedance (input voltage 0.7 V_{pp} ; f = 1MHz) with R_{load} = 300 Ω		10		Ω
	Crosstalk between any inputs (R1 and R2 or B1 and B2 or G1 and G2) (input voltage $0.7V_{pp}$; f = 1MHz).	45	55		dB
	Crosstalk between any outputs (input voltage $0.7V_{pp}$; $f = 1MHz$)	40	55		dB
t _{dc}	Delay time between R, G, B inputs and RGB outputs.		10		ns
t _{sr1}	Switching Rise Time between FB1 Input Signal and R, G, B Output Signal (input signal on RGB1)		45		ns
t _{sf1}	Switching Fall Time between FB1 Input Signal and R, G, B Output Signal (input signal on RGB1)		25		ns
t _{sr2}	Switching Rise Time between FB2 Input Signal and R, G, B Output Signal (input signal on RGB2)		55		ns
t _{sf2}	Switching Fall Time between FB2 Input Signal and R, G, B Output Signal (input signal on RGB2)		25		ns

Fast Blanking Switch (pin 13) (time measurement conditions: FB input pulse amplitude = 2 V, C pulse amplitude = 3V))

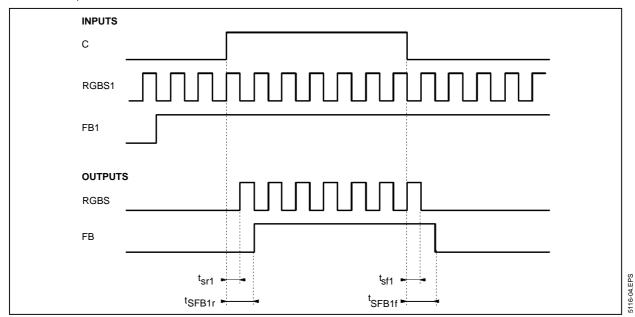
(4,1110 11104	time measurement conditions . 1 B input puise amplitude – 2 V, C puise amplitude – 3 V))							
V _{IL} V _{IH} V _{OL} V _{OH}	Low Level Input Voltage High Level Input Voltage Low Level Output Voltage High Level Output Voltage $T_{junction} = 25^{\circ}C$ $T_{junction} = 25^{\circ}C$	- 0.5 1 1.4 1.5	1.7 1.9	0.4 V _{CC} +0.5 V _{CC} +0.5 3.5	V V V			
	Dynamic Output Impedance : with $R_{load} = 300\Omega$	1.0	10		Ω			
t _{FB1r}	Delay Rise Time between FB1 Input and FB Output		60	110	ns			
t _{FB1f}	Delay Fall Time between FB1 Input and FB Output		40	60	ns			
t _{FB2r}	Delay Rise Time between FB2 Input and FB Output		60		ns			
t _{FB2f}	Delay Fall Time between FB2 input and FB Output		40		ns			
tSFB1r	Switching Rise Time between C Input and FB Output (input signal on FB1 input)		75		ns			
t _{SFB1f}	Switching Fall Time between C Input and FB Output (input signal on FB1 input)		50		ns			
t _{SFB2r}	Switching Rise Time between C Input and FB Output (input signal on FB2 input)		85		ns			
t _{SFB2f}	Switching Fall Time between C Input and FB Output (input signal on FB2 input)		50		ns			

ELECTRICAL CHARACTERISTICS (continued)

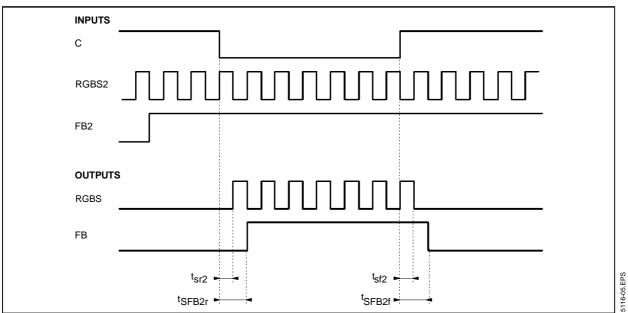
Symbol	Parameter	Min.	Тур.	Max.	Unit		
Video (or synchro) Signal Switch (pin 15) - time measurement conditions : (C pulse amplitude = 3V)							
Vs	DC Output Voltage (no input voltage)						
	T _{junction} = 25°C		0.9 1.2	1.25	V		
Vas	T _{junction} stabilized Max Output Swing Voltage	2.6	1.2		V_{pp}		
Z _{ic}	DC Input Impedance		10		kΩ		
Z_{cc}	Dynamic Output Impedance (input voltage $1V_{pp}$; f = $1MHz$) with $R_{load} = 300 \Omega$		10		Ω		
A _V B	Gain (input voltage 1 V _{pp} ; f = 1MHz) Bandwidth (– 3 dB) (input voltage 1 V _{pp})	5.5 15	6 20	6.5	dB MHz		
	Input Swing		1V ± 3 dB				
t _{dc}	Delay Time between S Input and S Output (∆ input : 0.7V _{PP})		10		ns		
t _{sr1}	Switching rise time between C input signal and S output signal (input signal on S1)		45		ns		
t _{sf1}	Switching fall time between C input signal and S output signal (input signal on S1)		25		ns		
t _{sr2}	Switching Rise time between C input signal and S output signal (input signal on S2)		55				
t _{sf2}	Switching fall time between C input signal and S output signal (input signal on S2)		25				
Select Inpu	t "C" (pin 3)						
VIL	Low Level Input Voltage	- 0.5		1	V		
ViH	High Level Input Voltage	2		Vcc+0.5	V m^		
ļı∟	Low Level Input Current (V _{IL} = 1 V)	- 0.6		- 0.1	mΑ		



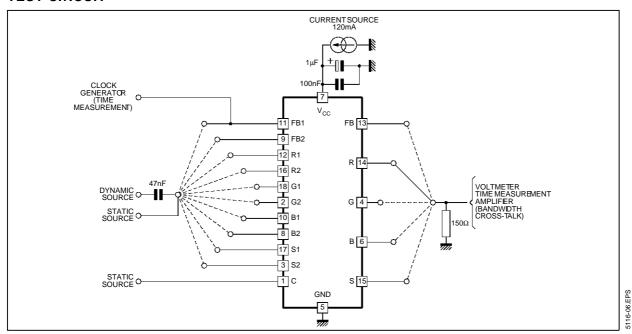
RGBS2 = 0, FB2 = 0



RGBS1 = 0, FB1 = 0

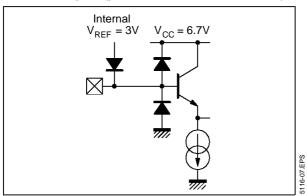


TEST CIRCUIT

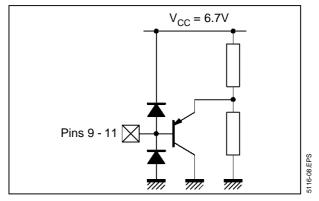


INPUTS/OUTPUTS EQUIVALENT INTERNAL DIAGRAMS

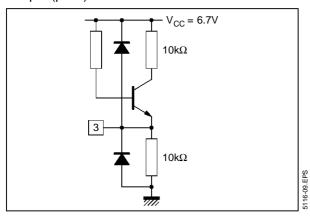
R, G, B, S inputs (pins 1, 2, 8, 10, 12, 16, 17, 18)



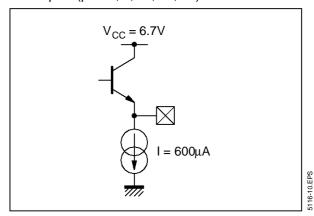
FB inputs (pins 9, 11)



C input (pin 3)



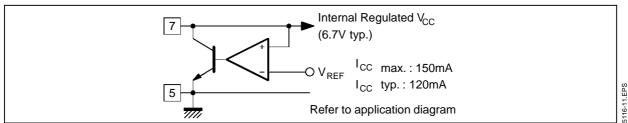
All Outputs (pins 4, 6, 13, 14, 15)



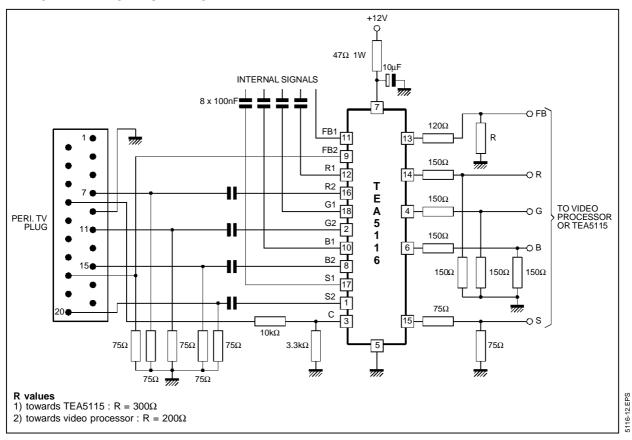
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INPUTS/OUTPUTS EQUIVALENT INTERNAL DIAGRAMS (continued)

I_{CC} Supply (shunt transistor regulation system) (Pin 7)



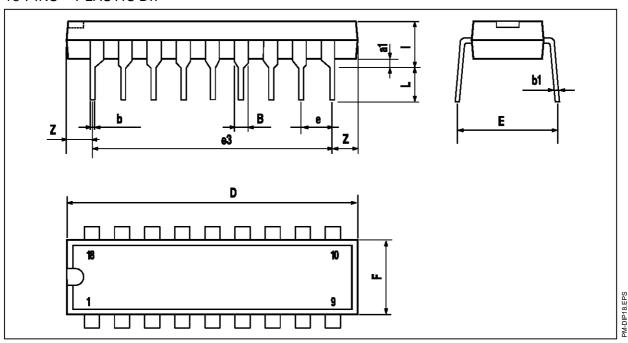
TYPICAL APPLICATION DIAGRAM



- Above given output load values are minimum values, in case of all output loading.
- Minimum output load is 150 Ω individually, provided that total supply current is less than 150 mA.

PACKAGE MECHANICAL DATA

18 PINS - PLASTIC DIP



Dimensions		Millimeters			Inches	
	Min.	Тур.	Max.	Min.	Тур.	Max.
a1	0.254			0.010		
В	1.39		1.65	0.055		0.065
b		0.46			0.018	
b1		0.25			0.010	
D			23.24			0.915
E		8.5			0.335	
е		2.54			0.100	
e3		20.32			0.800	
F			7.1			0.280
I			3.93			0.155
L		3.3			0.130	
Z		1.27	1.59		0.050	0.063

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